

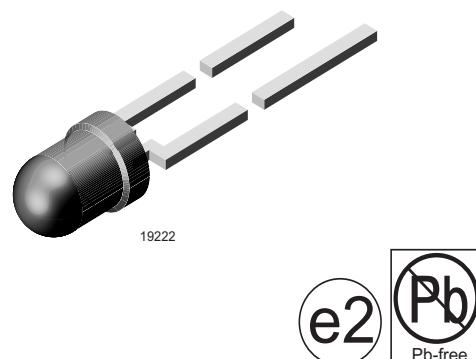
High Intensity LED in \varnothing 3 mm Tinted Diffused Package

Description

This device has been designed to meet the increasing demand for AlInGaP technology general indicating and lighting purposes

It is housed in a 3 mm diffused plastic package. The wide viewing angle of these devices provides a high brightness.

All packing units are categorized in luminous intensity and color groups. That allows users to assemble LEDs with uniform appearance.



Features

- AlInGaP technology
- Standard \varnothing 3 mm (T-1) package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Wide viewing angle
- Very high intensity
- Luminous intensity color categorized
- Lead-free device

Applications

- Status lights
- OFF / ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ($\pm\phi$)	Technology
TLHF4600	Soft Orange, $I_V > 10$ mcd	60 °	AlInGaP on GaAs

Absolute Maximum Ratings

$T_{amb} = 25$ °C, unless otherwise specified
TLHF4600

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	5	V
DC Forward current	$T_{amb} \leq 60$ °C	I_F	30	mA
Surge forward current	$t_p \leq 10$ μ s	I_{FSM}	0.1	A
Power dissipation	$T_{amb} \leq 60$ °C	P_V	80	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 55 to + 100	°C
Soldering temperature	$t \leq 5$ s, 2 mm from body	T_{sd}	260	°C
Thermal resistance junction/ambient		R_{thJA}	400	K/W

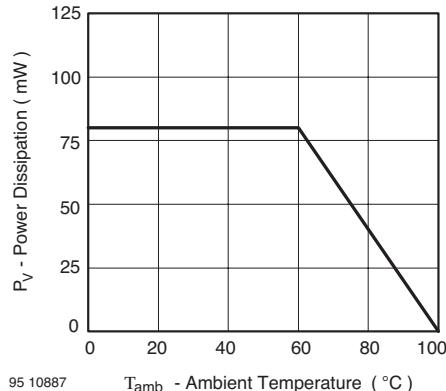
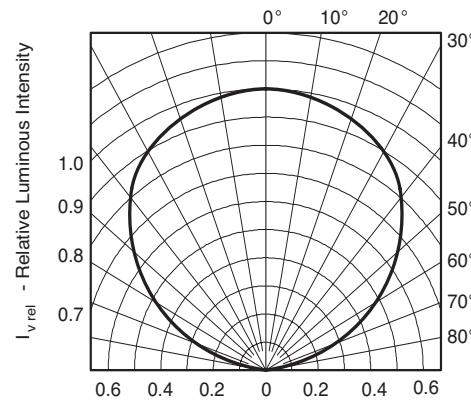
Optical and Electrical Characteristics

 $T_{amb} = 25 \text{ }^{\circ}\text{C}$, unless otherwise specified

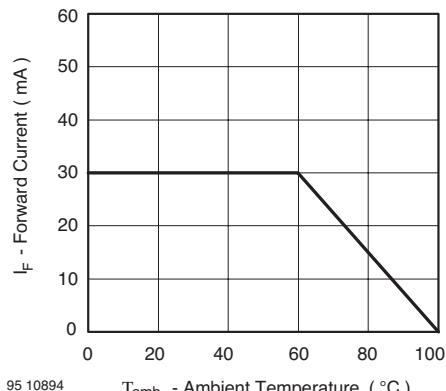
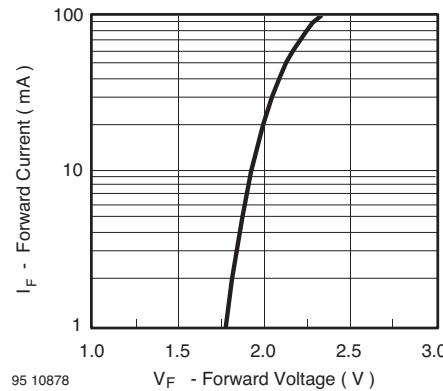
Soft Orange

TLHF4600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	$I_F = 10 \text{ mA}$	I_V	10	26		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$	λ_d	598	605	611	nm
Peak wavelength	$I_F = 10 \text{ mA}$	λ_p		610		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	φ		± 60		deg
Forward voltage	$I_F = 20 \text{ mA}$	V_F		1.9	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$	V_R	5			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		15		pF

¹⁾ in one Packing Unit $I_V \text{min}/I_V \text{max} \leq 0.5$ Typical Characteristics ($T_{amb} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified)95 10887 T_{amb} - Ambient Temperature (°C)

95 10043

95 10894 T_{amb} - Ambient Temperature (°C)95 10878 V_F - Forward Voltage (V)

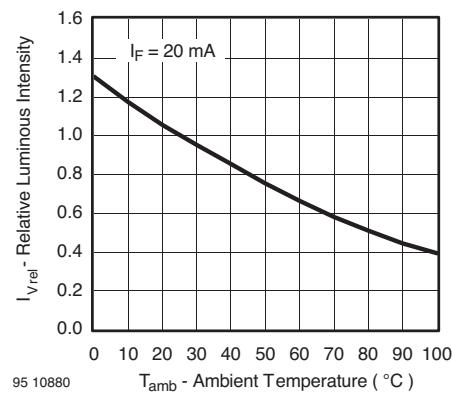


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

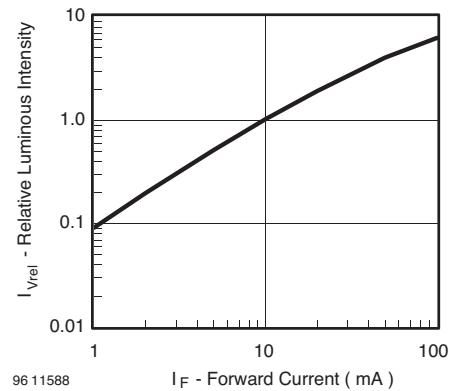


Figure 6. Relative Luminous Intensity vs. Forward Current

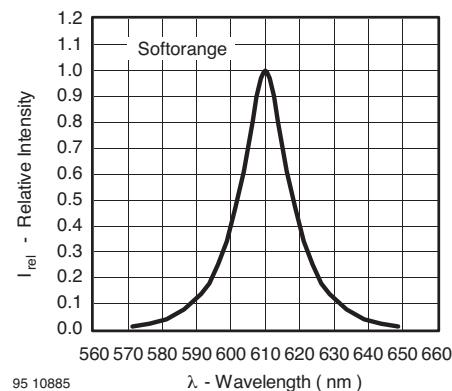
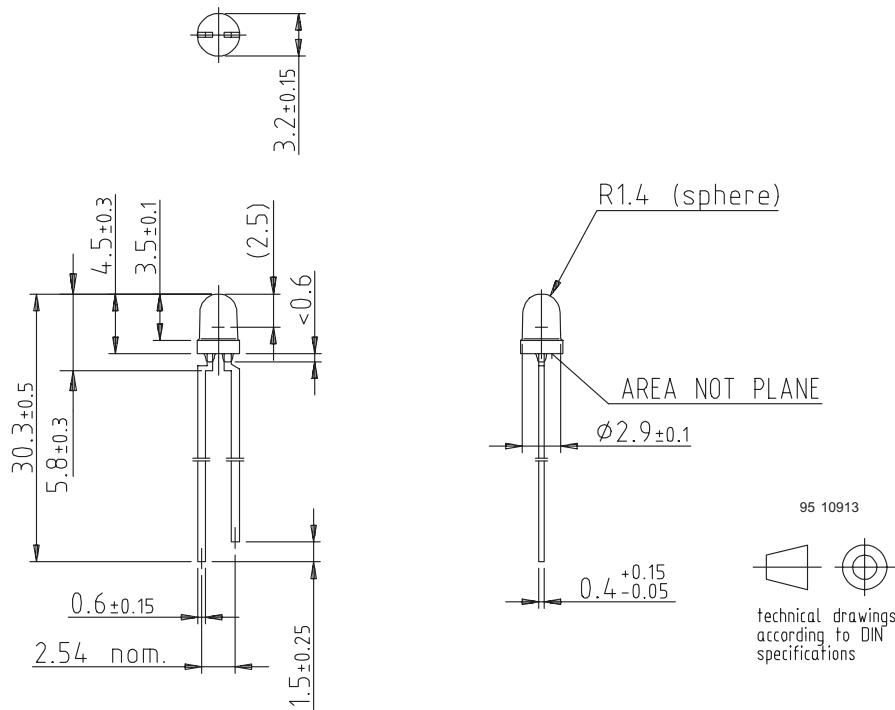


Figure 7. Relative Intensity vs. Wavelength

Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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